AMP1029B
SOLID STATE HIGH POWER AMPLIFIER

FEATURES

Class AB linear GaN design
Instantaneous wide bandwidth
Suitable for all single channel modulations standards
Small form factor & light weight
Built-in protection circuits
High reliability and ruggedness

ELECTRICAL SPECIFICATIONS: 50 Ω, 25°C

Parameter	Specification	Notes
Operating Frequency Range	2.0 - 6.0 GHz	
Power Output	50 Watt Min	CW
Power Output @ P1dB	40 Watt Min	CW
Power Gain	47 dB Min	
Power Gain Flatness	3.0 dB p-p Max	Constant input power
Input / Output Return Loss	-10 dB Max	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	<-30 dBc Typ	37dBm/Tone, Δ = 1 MHz
Harmonics	<-20 dBc Typ	At rated Pout
Spurious	-60 dBc Max	Non-harmonics
Operating Voltage	28 - 30 VDC	
Current Consumption	10 Amp Max	At rated Pout
Max Input Power	+8 dBm	10 Sec Without damage
Load VSWR Protection	∞ : 1	1 Minute @ rated output

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +75 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	230 x 106 x 27 mm	Excluding connectors
Weight	1.25 Kg.	
RF Connectors In/Out	SMA female	
DC Power / Interface Connector	9-Pin D-Sub	
Cooling	External Heatsink	Forced air required

D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	FWD	OPTION 101 - Forward power detect
2	VVA	OPTION 103 - Variable Voltage Attenuator
3	CURRENT SENSOR	I_D@20mV/100mA Typ
4	TEMP SENSOR	V_T@10mV/°C + 500mV Typ
5	SHUTDOWN	TTL - Optional 5µS switching speed
6, 7	VDD	28VDC
8, 9	GND	Ground

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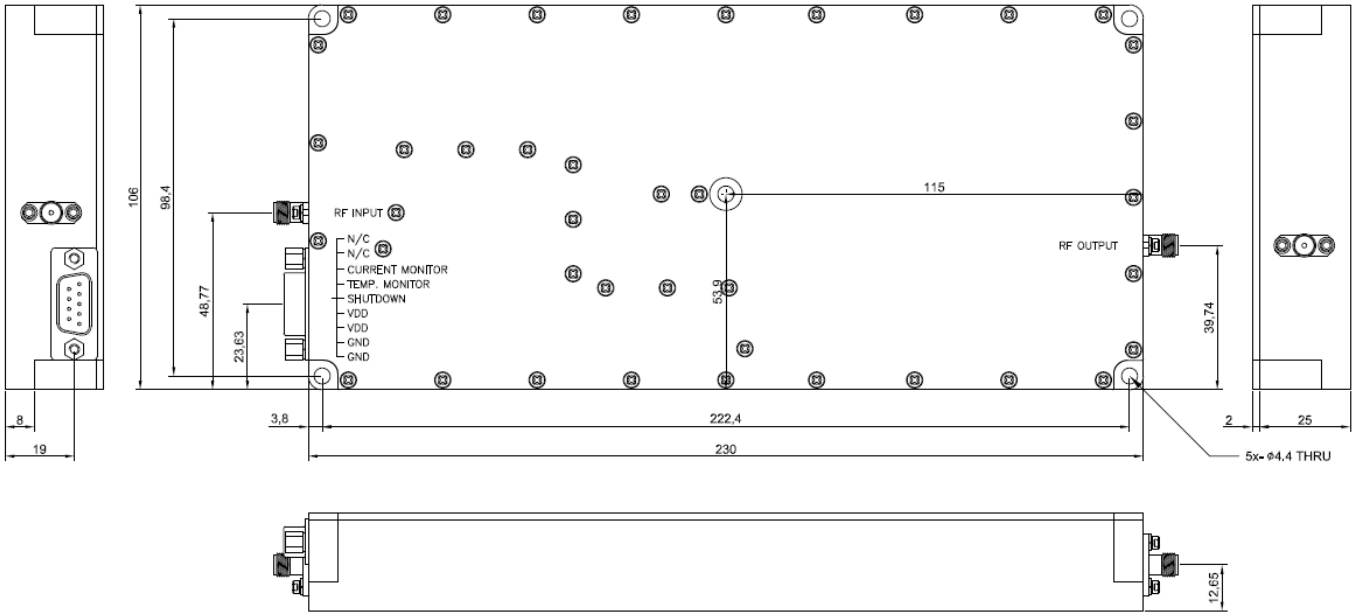
OUTLINE DRAWING